

**GaAs SPDT Terminated Switch
DC - 2.5 GHz**

**SW-338
V6**

Features

- Very Low Power Consumption
- High Isolation: 30 dB up to 2 GHz
- Very High Intercept Point: 46 dBm IP₃
- Nanosecond Switching Speed
- Temperature Range: -40°C to +85°C
- Low Cost SOIC-8 Plastic Package
- Tape and Reel Packaging Available

Description

M/A-COM's SW-338 is a GaAs MMIC SPDT terminated switch in a low cost SOIC 8-lead surface mount plastic package. The SW-338 is ideally suited for use where very low power consumption is required.

Typical applications include transmit/receive switching, switch matrices, and filter banks in systems such as radio and cellular equipment, PCM, GPS, fiber optic modules, and other battery powered radio equipment.

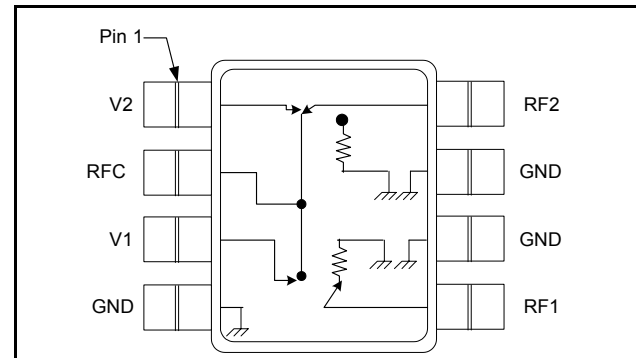
The SW-338 is fabricated with a monolithic GaAs MMIC using a mature 1-micron process. The process features full chip passivation for increased performance and reliability.

Ordering Information

| Part Number | Package |
|-------------|-------------------|
| SW-338 | Bulk Packaging |
| SW-338TR | 1000 piece reel |
| SW-338SMB | Sample Test Board |

Note: Reference Application Note M513 for reel size information.

Functional Schematic



Pin Configuration

| Pin No. | Function | Pin No. | Function |
|---------|-----------|---------|-----------|
| 1 | V2 | 5 | RF Port 1 |
| 2 | RF Common | 6 | Ground |
| 3 | V1 | 7 | Ground |
| 4 | Ground | 8 | RF Port 2 |

Absolute Maximum Ratings ^{1,2}

| Parameter | Absolute Maximum |
|--|--------------------------------|
| Input Power 0.05 GHz 0.5 - 2.0 GHz | +27 dBm +34 dBm |
| Control Voltage | -8.5 V ≤ V _c ≤ +5 V |
| Operating Temperature | -40°C to +85°C |
| Storage Temperature | -65°C to +150°C |

1. Exceeding any one or combination of these limits may cause permanent damage to this device.
2. M/A-COM does not recommend sustained operation near these survivability limits.

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Electrical Specifications: $T_A = 25^\circ\text{C}$, $V_c = 0\text{ V} / -2.9\text{ V}$, $Z_0 = 50\ \Omega$

| Parameter | Test Conditions | Units | Min. | Typ. ³ | Max. |
|------------------------|---|---------------|------|-------------------|------|
| Insertion Loss | DC - 0.5 GHz | dB | — | 0.55 | — |
| | 0.5 - 1.0 GHz | dB | — | 0.60 | 0.7 |
| | 1.0 - 2.0 GHz | dB | — | 0.65 | — |
| Isolation | DC - 0.5 GHz | dB | — | 50 | — |
| | 0.5 - 1.0 GHz | dB | 36 | 43 | — |
| | 1.0 - 2.0 GHz | dB | — | 35 | — |
| VSWR On/Off | DC - 2.0 GHz | Ratio | — | 1.1:1 | — |
| Trise, Tfall | 10% to 90% RF, 90% to 10% RF | nS | — | 10 | — |
| Ton, Toff | 50% Control to 90% RF, 50% Control to 10% RF | nS | — | 20 | — |
| Transients | In-Band | mV | — | 25 | — |
| 1 dB Compression Point | Input Power | dBm | — | 25 | — |
| | 0.05 GHz 0.5 - 2.0 GHz | dBm | — | 30 | — |
| 2nd Order Intercept | Measured Relative to Input Power (for two-tone input power up to +5 dBm) | dBm | — | 60 | — |
| | 0.05 GHz 0.5 - 2.0 GHz | dBm | — | 65 | — |
| 3rd Order Intercept | Measured Relative to Input Power (for two-tone input power up to +5 dBm) | dBm | — | 40 | — |
| | 0.05 GHz 0.5 - 2.0 GHz | dBm | — | 46 | — |
| Control Current | $ V_c = 2.9\text{ V}$ | μA | — | 15 | 35 |

3. Typical values represent performance at middle of frequency range noted.

Truth Table⁴

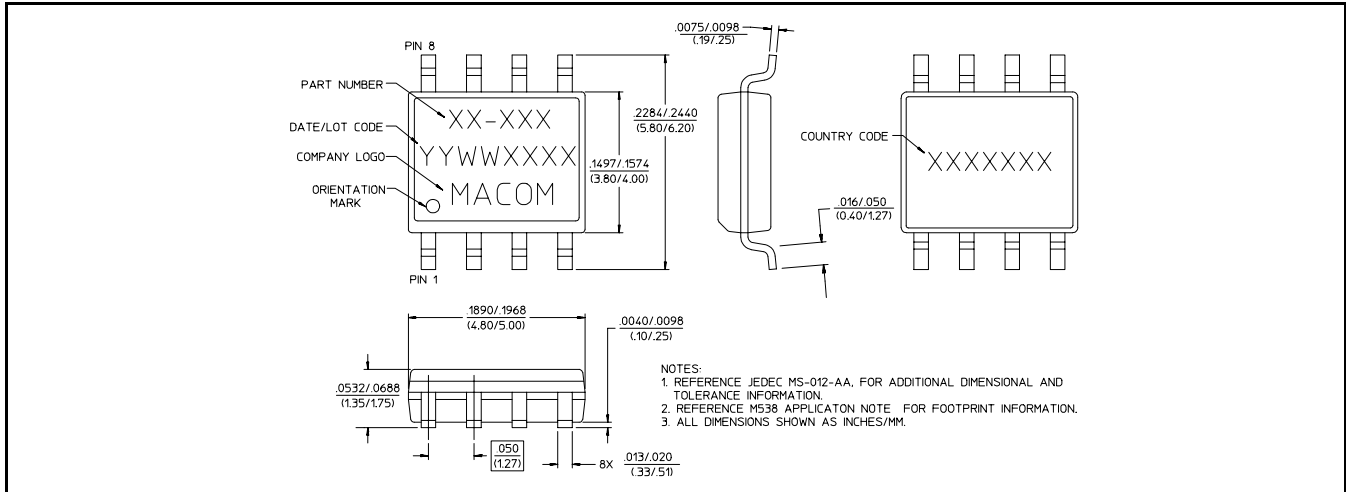
| Control Inputs | | Condition of Switch RF Common to Each RF Port | |
|----------------|----|--|---------|
| V1 | V2 | RFC-RF1 | RFC-RF2 |
| 1 | 0 | ON | OFF |
| 0 | 1 | OFF | ON |

4. 0 = 0 V \pm 0.2 V, 1 = -2.9 V to -5.0 V

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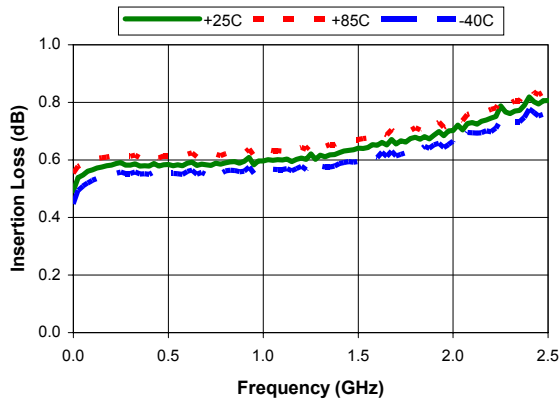
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SO-8

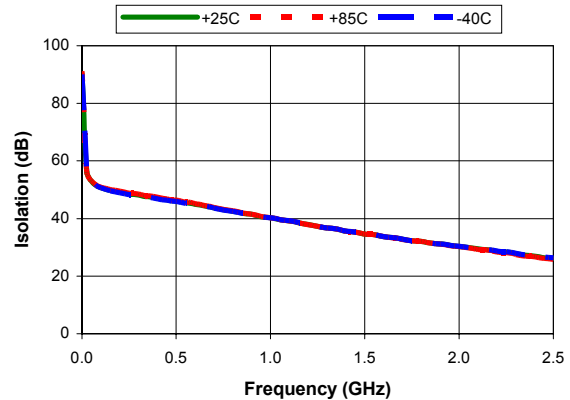


Typical Performance Curves

Insertion Loss



Isolation



VSWR vs. Frequency

